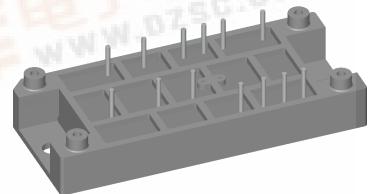
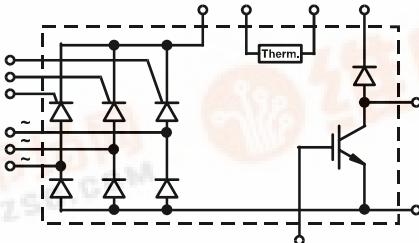




Three Phase Half Controlled Rectifier Bridge with IGBT and Fast Recovery Diode for Braking System

$V_{RRM} = 1200-1600 \text{ V}$
 $I_{dAV} = 120 \text{ A}$

V_{RRM}	Type
1200	VVZB 120-12 io1
1400	VVZB 120-14 io1
1600	VVZB 120-16 io1



Symbol	Conditions	Maximum Ratings		
I_{dAV} I_{FRMS}/I_{TRMS}	$T_{case} = 80^\circ\text{C}$, sinusoidal 120°	120	A	
	$T_{case} = 80^\circ\text{C}$, per leg	77	A	
I_{FSM}/I_{TSM}	$T_{VJ} = 25^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	750	A	
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	670	A	
I^2t	$T_{VJ} = 25^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	2810	A	
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$, $V_R = 0 \text{ V}$	2240	A	
$(di/dt)_{cr}$	$T_{VJ} = T_{VJM}$ repetitive, $I_T = 150 \text{ A}$	150	$\text{A}/\mu\text{s}$	
	$f = 50 \text{ Hz}$, $t_p = 200 \mu\text{s}$			
$(dv/dt)_{cr}$	$V_D = \frac{2}{3} V_{DRM}$			
	$I_G = 0.45 \text{ A}$, non repetitive, $I_T = I_{d(AV)}/3$	500	$\text{A}/\mu\text{s}$	
P_{GM}	$T_{VJ} = T_{VJM}$; $V_{DR} = \frac{2}{3} V_{DRM}$	1000	$\text{V}/\mu\text{s}$	
	$R_{GK} = \infty$; method 1 (linear voltage rise)			
P_{GAVM}	$T_{VJ} = T_{VJM}$	10	W	
	$I_T = I_{d(AV)}/3$	5	W	
	$t_p = 10 \text{ ms}$	1	W	
V_{CES} V_{GE}		0.5	W	
I_{C25} I_{C80} I_{CM}	$T_{VJ} = 25^\circ\text{C}$ to 150°C	1200	V	
	Continuous	± 20	V	
	$T_{case} = 25^\circ\text{C}$, DC	78	A	
	$T_{case} = 80^\circ\text{C}$, DC	52	A	
P_{tot}	$t_p = \text{Pulse width limited by } T_{VJM}$	140	A	
V_{RRM}		222	W	
$I_{F(AV)}$ $I_{F(RMS)}$ I_{FRM}		1200	V	
	$T_{case} = 80^\circ\text{C}$, rectangular $d = 0.5$	27	A	
	$T_{case} = 80^\circ\text{C}$, rectangular $d = 0.5$	38	A	
	$T_{case} = 80^\circ\text{C}$, $t_p = 10 \mu\text{s}$, $f = 5 \text{ kHz}$	tbd	A	
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$, $t = 10 \text{ ms}$	200	A	
	$T_{VJ} = 150^\circ\text{C}$, $t = 10 \text{ ms}$	180	A	
P_{tot}	$T_{case} = 80^\circ\text{C}$	64	W	

Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions.

Features

- Soldering connections for PCB mounting
- Isolation voltage 3600 V~
- Ultrafast freewheel diode
- Convenient package outline

Applications

- Drive Inverters with brake system

Advantages

- 2 functions in one package
- No external isolation
- Easy to mount with two screws
- Suitable for wave soldering
- High temperature and power cycling capability

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ C$, unless otherwise specified)		
Rectifier Bridge	$V_R = V_{RRM}/V_{DRM}$, $V_R = V_{RRM}/V_{DRM}$, $T_{VJ} = 150^\circ C$ $I_F = 100 A$, For power-loss calculations only $T_{VJ} = 150^\circ C$ $V_D = 6 V$; $T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$ $V_D = 6 V$; $T_{VJ} = 25^\circ C$ $T_{VJ} = -40^\circ C$ $T_{VJ} = T_{VJM}$; $V_D = \frac{2}{3} V_{DRM}$ $T_{VJ} = T_{VJM}$; $V_D = \frac{2}{3} V_{DRM}$ $V_D = 6 V$; $t_G = 30 \mu s$ $di_G/dt = 0.45 A/\mu s$; $I_G = 0.45 A$ $T_{VJ} = T_{VJM}$; $V_D = 6 V$; $R_{GK} = \infty$ $V_D = \frac{1}{2} V_{DRM}$ $di_G/dt = 0.45 A/\mu s$; $I_G = 0.45 A$ $T_{VJ} = T_{VJM}$; $V_R = 100 V$; $V_D = \frac{2}{3} V_{DRM}$; $t_p = 200 \mu s$ $dv/dt = 10 V/\mu s$; $I_T = 120 A$; $-di/dt = 10 A/\mu s$ $T_{VJ} = T_{VJM}$ $-di/dt = 0.64 A/\mu s$; $I_T/I_F = 50 A$ per thyristor / diode; sine 120° el. per thyristor / diode; sine 120° el.	min.	typ.	max.
			0.3	mA
			5	mA
			1.47	V
			0.85	V
			5	mΩ
			1.5	V
			1.6	V
			100	mA
			200	mA
			0.2	V
			10	mA
			450	mA
			200	mA
IGBT	$V_{GS} = 0 V$, $I_C = 1 mA$ $I_C = 10 mA$ $V_{GE} = \pm 20 V$ $V_{CE} = 0.8 V_{CES}$ $V_{CE} = 0.8 V_{CES}, T_{VJ} = 150^\circ C$ $V_{GE} = 15 V$, $I_C = 50 A$ $V_{GE} = 15 V$, $V_{CE} = 0.6 V_{CES}$, $T_{VJ} = 125^\circ C$, $R_G = 11 \Omega$, non repetitive $V_{GE} = 15 V$, $V_{CE} = 0.8 V_{CES}$, $T_{VJ} = 125^\circ C$, $R_G = 11 \Omega$, Clamped Inductive load, $L = 100 \mu H$ $V_{CE} = 25 V$, $f = 1 MHz$, $V_{GE} = 0 V$ $V_{CE} = 0.6 V_{CES}$, $I_C = 25 A$ $V_{GE} = 15 V$, $R_G = 11 \Omega$ Inductive load; $L = 100 \mu H$ $T_{VJ} = 125^\circ C$	1200		V
		5	8	V
			500	nA
			0.5	mA
			3	mA
			3.35	V
			10	μs
			100	A
			9	nF
			65	ns
$t_{d(on)}$	$t_{d(off)}$ t_{ri} t_{fi} E_{on} E_{off}	$V_{CE} = 0.6 V_{CES}$, $I_C = 25 A$ $V_{GE} = 15 V$, $R_G = 11 \Omega$ Inductive load; $L = 100 \mu H$ $T_{VJ} = 125^\circ C$	200	ns
			tbd	ns
			tbd	ns
			4.1	mJ
			5.7	mJ
R_{thJC}	R_{thJH}		0.32	KW
			0.45	KW

Symbol	Conditions	Characteristic Values		
		($T_{VJ} = 25^\circ\text{C}$, unless otherwise specified)		
I_R	$V_R = V_{RRM}, T_{VJ} = 25^\circ\text{C}$ $V_R = 0.8 V_{RRM}, T_{VJ} = 150^\circ\text{C}$	3	0.75 mA 7 mA	
V_F	$I_F = 30 \text{ A}, T_{VJ} = 25^\circ\text{C}$		2.55 V	
V_{TO} r_T	For power-loss calculations only $T_{VJ} = 150^\circ\text{C}$		1.65 V 18.2 mΩ	
I_{RM}	$I_F = 30 \text{ A}, -di_F/dt = 240 \text{ A}/\mu\text{s}$ $V_R = 100 \text{ V}$	16	18 A	
t_{rr}	$I_F = 1 \text{ A}, -di_F/dt = 100 \text{ A}/\mu\text{s}$ $V_R = 30 \text{ V}$	40	60 ns	
R_{thJC} R_{thJH}			1.1 kW 1.5 kW	
Common Specification		Maximum Ratings		
T_{VJ}		-40...+150	$^\circ\text{C}$	
T_{VJM}		150	$^\circ\text{C}$	
T_{stg}		-40...+125	$^\circ\text{C}$	
V_{ISOL}	50/60 Hz $I_{ISOL} \leq 1 \text{ mA}$	t = 1 min t = 1 s	3000 V~ 3600 V~	
M_d	Mounting torque (M5) (10-32 unf)	(M5) (10-32 unf)	2-2.5 Nm 18-22 lb.in.	
Weight	typ.		80 g	
d_s	Creep distance on surface		12.7 mm	
d_A	Strike distance in air		11 mm	
a	Maximum allowable acceleration		50 m/s ²	
R_{25} $B_{25/100}$	Thermistor		2.1 kΩ 3560 K	

Dimensions in mm (1 mm = 0.0394")
